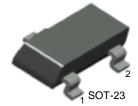


# KST1009F1/F2/F3/F4/F5

## **AM/FM RF Amplifier Transistor**



1. Base 2. Emitter 3. Collector

# **NPN Epitaxial Silicon Transistor**

## Absolute Maximum Ratings Ta=25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V <sub>CBO</sub>	Collector-Base Voltage	50	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	25	V	
V <sub>EBO</sub>	Emitter-Base Voltage	5	V	
I <sub>C</sub>	Collector Current	50	mA	
P <sub>C</sub>	Collector Dissipation	350	mW	
T <sub>STG</sub>	Storage Temperature	150	°C	

# Electrical Characteristics $T_a=25$ °C unless otherwise noted

	a					
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> =15V, I <sub>E</sub> =0			100	nA
h <sub>FE</sub>	DC Current Gain					
	: KST1009F1	$V_{CE}=3V$ , $I_{C}=0.5mA$	30		60	
	: KST1009F2		40		80	
	: KST1009F3		60		120	
	: KST1009F4		90		180	
	: KST1009F5		135		270	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =10mA, I <sub>B</sub> =1mA			0.3	V
f <sub>T</sub>	Current Gain Bandwidth Product	I <sub>C</sub> =1mA, V <sub>CE</sub> =6V	150			MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =6V, I <sub>E</sub> =0, f=1MHz		2		pF
NF	Noise Figure	$V_{CE}=6V$ , $I_{C}=0.5mA$		2.5		dB
		$f=1MHz$ , $R_G=500\Omega$				

## **Marking Code**

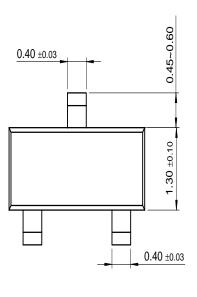
Type	KST1009F1	KST1009F2	KST1009F3	KST1009F4	KST1009F5
Mark	F1	F2	F3	F4	F5

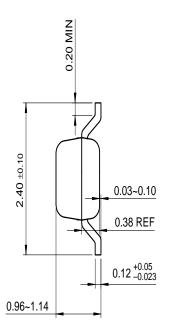


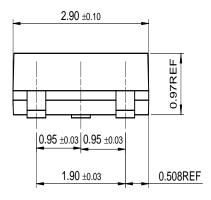
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# **Package Demensions**

# **SOT-23**







Dimensions in Millimeters

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FAST<sup>®</sup> Quiet Series<sup>™</sup>
FASTr<sup>™</sup> SuperSOT<sup>™</sup>-3
GTO<sup>™</sup> SuperSOT<sup>™</sup>-6

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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